





WE4C-2

Linearity Enhanced Broadband Darlington Power Amplifier IC Using InGaP-GaAs HBT for Handset Modules with Fractional Bandwidth of 50%

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- Introduction
- Design and Analysis
 - Broadband Darlington Power Amplifiers
 - Linearization 1: Using Input Transformer and C_{be}
 - Linearization 2: Using Diodes and Capacitors
- Implementation and Experimental Results
- Conclusion







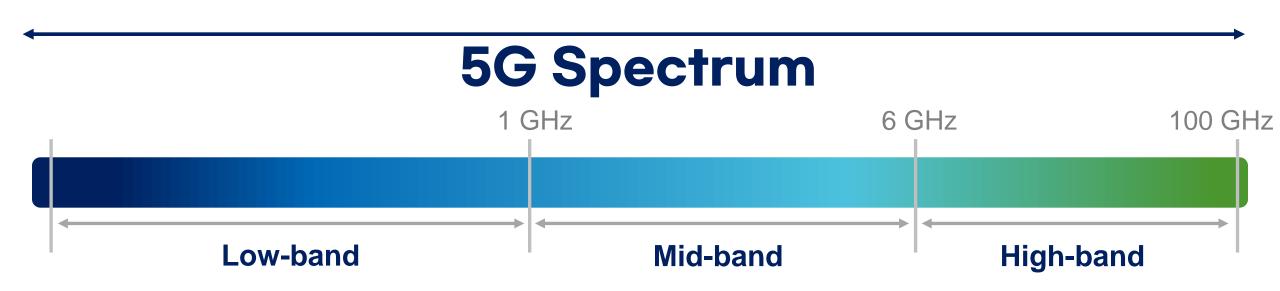
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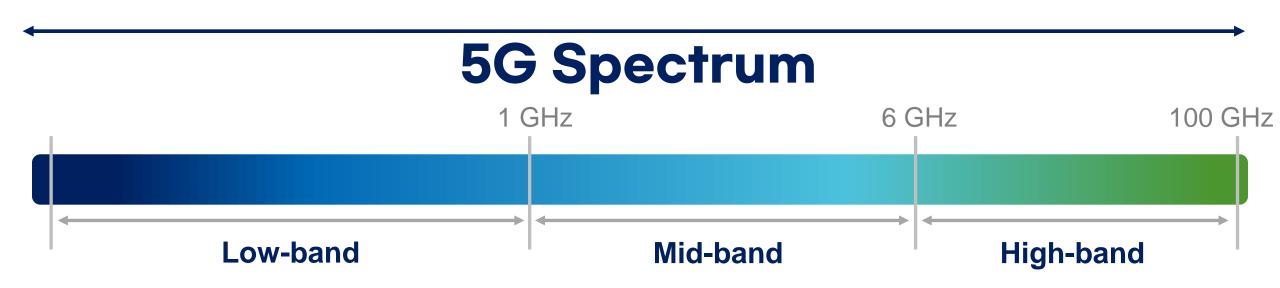


Why All Three Spectrum Layers Are Vital to 5G?









Why All Three Spectrum Layers Are Vital to 5G?

Three properties that determine the performance of 5G

Bandwidth

Latency

Coverage

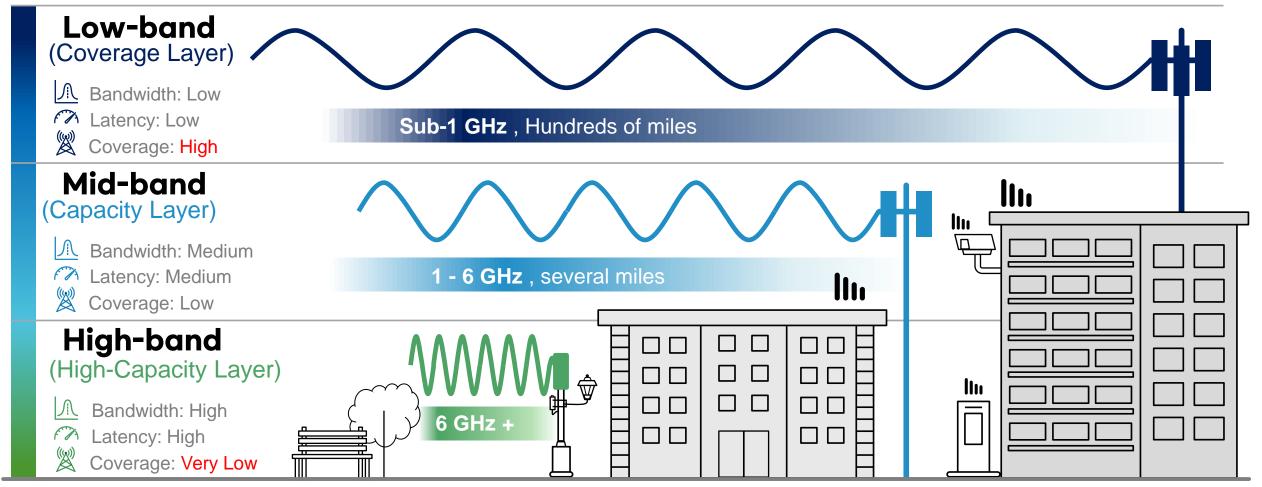
"What Is Low, Mid, and High-Band? The 5G Spectrum Layers Explained," westbase.io, accessed May 2. 2023, https://www.westbase.io/blog/what-is-low-mid-and-high-band-the-5g-











The reality of 5G in various scenarios is that all three spectrum layers are mixed so that users get the right blend of coverage and performance for their given situation.













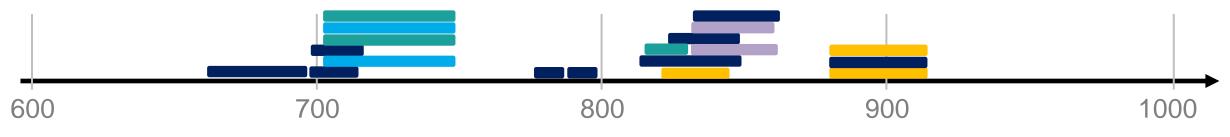




Uplink(MHz)



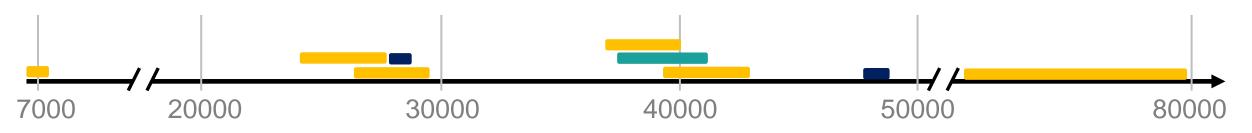
Low-band(Sub-1GHz)



Mid-band(1-6 GHz)



High-band(6 GHz +)



"5G NR frequency band," sqimway, accessed May 2. 2023, https://www.sqimway.com/nr_band.php





Uplink(MHz)

















iPhone 14 Pro 'Cellular and Wireless'

- 5G NR (Bands n1, n2, n3, n5, n7, n8, n12, n14, n20, n25, n26, n28, n29, n30, n38, n40, n41, n48, n53, n66, n70, n71, n77, n78, n79)
- 5G NR mmWave (Bands n258, n260, n261)
- FDD-LTE (Bands 1, 2, 3, 4, 5, 7, 8, 12, 13, 14, 17, 18, 19, 20, 25, 26, 28, 29, 30, 32, 66, 71)
- TD-LTE (Bands 34, 38, 39, 40, 41, 42, 46, 48, 53)
- UMTS/HSPA+/DC-HSDPA (850, 900, 1700/2100, 1900, 2100 MHz)
- GSM/EDGE (850, 900, 1800, 1900 MHz)

40000

30000

50000

80000

7000



20000





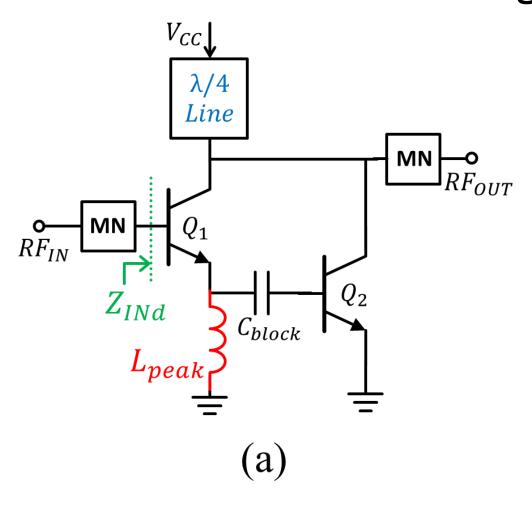
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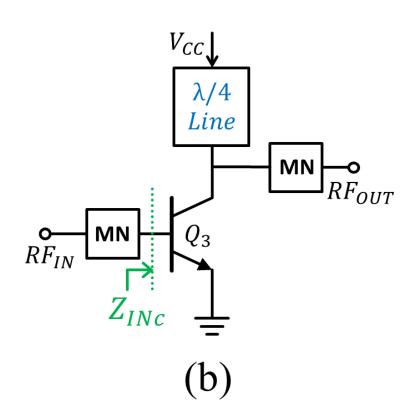


Design and Analysis: Broadband Darlington Power Amplifiers





Darlington



Common-emitter







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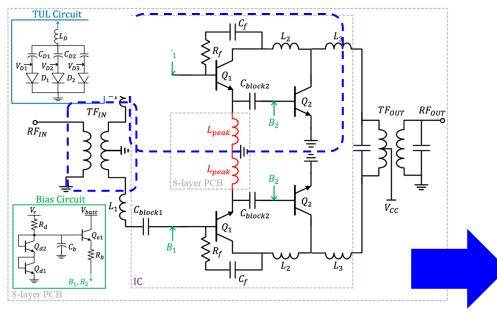


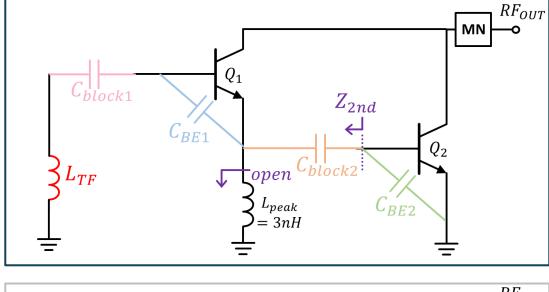


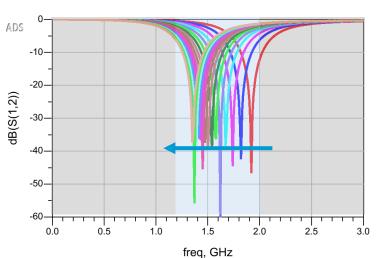
Design and Analysis:

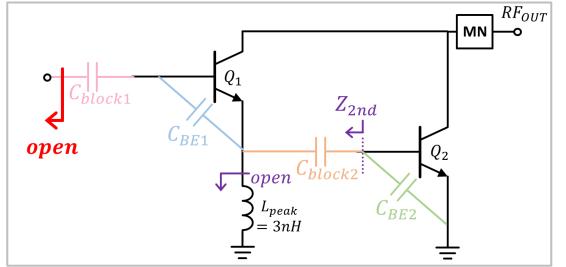


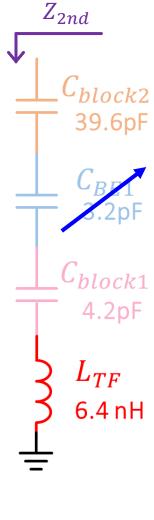
Linearization 1: Using Input Transformer and Cbe

















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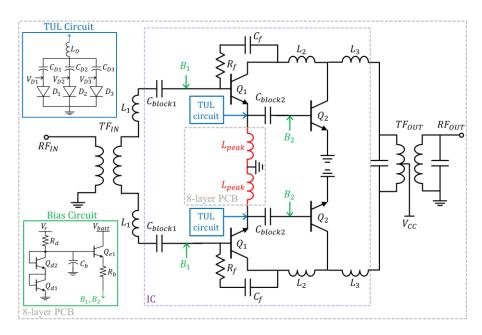


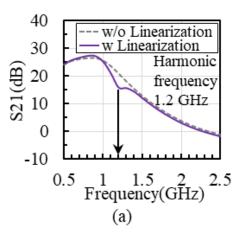


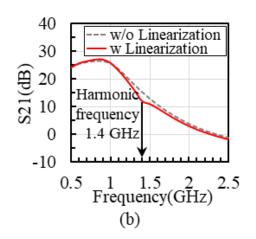
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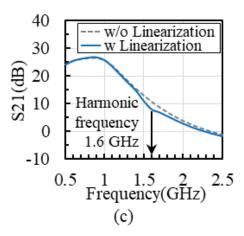


Linearization 2: Using Diodes and Capacitors

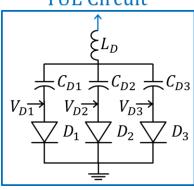




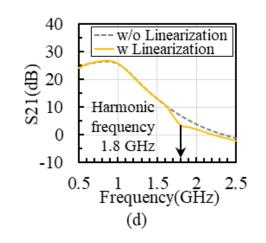


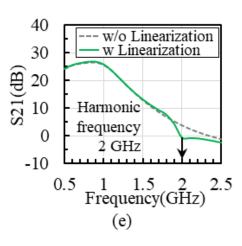


TUL Circuit



	V_{D1}	V_{D2}	V_{D3}	
(a)	3 V	3 V	0 V	
(b)	3 V	0 V	0 V	
(c)	0 V	3 V	0 V	
(d)	0 V	0 V	3 V	
(e)	0 V	0 V	0 V	











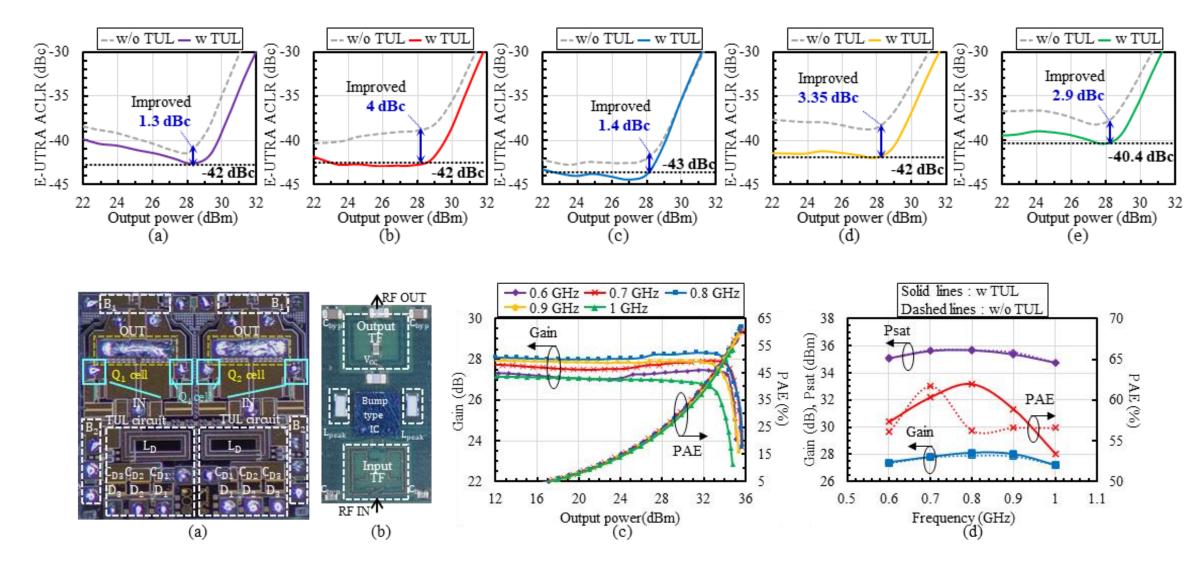
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Implementation and Experimental Results











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Conclusion



Table 1. Performance comparison to the previously reported GaAs HBT ICs.

Ref.	2014 [18]	2016 [19]	2020 [20]	2020 [21]	2022 [22]	This work
Freq. (GHz)	0.9	0.88	0.851 - 0.894	0.88- 0.915	0.728 - 0.768	0.6-1
Gain (dB)	31	29.2	36.5	29.5- 33	33.5- 34.5	27.2- 28.16
Psat (dBm)	29.6*	33.5	32	33.8- 34.5	35-36	34.7- 35.7
PAE _{peak} (%)	35*	46.1	12- 14 [#]	50-57	27- 31.5#	53.4- 62
ACLR (dBc)	-40 [*]	-45	-46.5	N/A	-30	-40
FBW (%)	N/A	N/A	5	4	5	50
Modulation	LTE 10 M	LTE 10 M	WCD MA 5 M	N/A	LTE 20 M	LTE 20 M

^{* :} performance of P1dB, \times : ACPR, # : PAE at Pavg







Thank You! Any Question?

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